

Low Capacitance Quad Array for ESD Protection

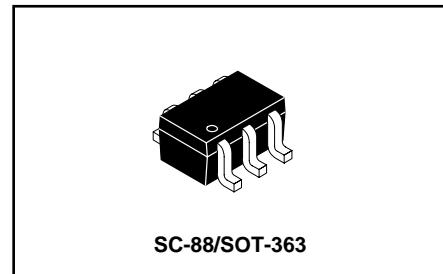
General Description

Low capacitance 5-fold ESD protection array in the very small SOT363 plastic package designed to protect up to five transmission or data lines from the damage caused by Electrostatic Discharge (ESD).

LESDA5VAW6T1G
S-LESDA5VAW6T1G

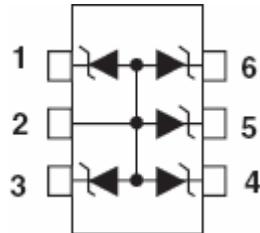
Applications

- Cellular handsets and accessories
- Portable electronics
- Computers and peripherals
- Communications systems
- Audio and video equipment.



Features

- Uni-directional ESD protection of up to five lines
- Bi-directional ESD protection of up to four lines
- Low diode capacitance
- Low clamping voltage
- low leakage current
- IEC 61000-4-2; level 4 (ESD)
- IEC61000-4-5 (surge)
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



ORDERING INFORMATION

Device	Marking	Shipping
LESDA5VAW6T1G S-LESDA5VAW6T1G	K4	3000/Tape & Reel

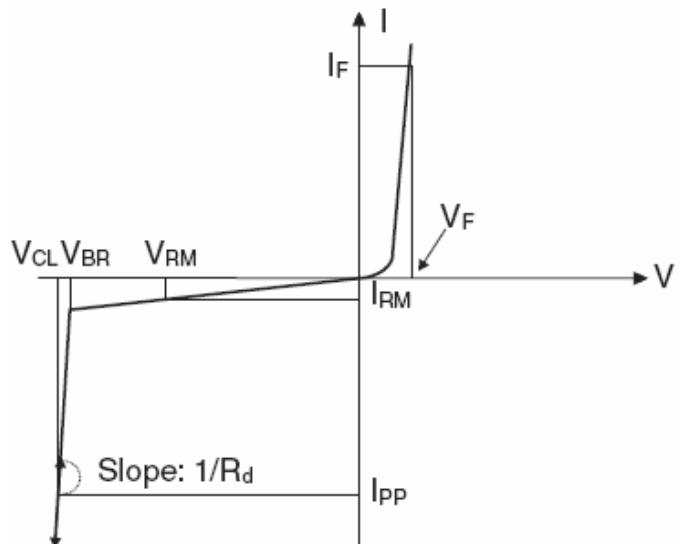
Absolute Ratings ($T_{amb}=25^{\circ}C$)

Symbol	Parameter	Value	Units
P_{PP}	Peak Pulse Power ($t_p = 8/20\mu s$)	25	W
T_L	Maximum lead temperature for soldering during 10s	260	°C
T_{stg}	Storage Temperature Range	-60 to +150	°C
T_{op}	Operating Temperature Range	-60 to +150	°C
T_j	Maximum junction temperature	150	°C
V_{PP}	Electrostatic discharge IEC61000-4-2 (contact discharge) IEC61000-4-2 (air discharge)	8 15	kV

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Electrical Parameter

Symbol	Parameter
V_{RM}	Stand-off voltage
V_{BR}	Breakdown voltage
V_{CL}	Clamping voltage
I_R	Leakage current
I_{PP}	Peak pulse current
C	Capacitance



Electrical Characteristics

Part Numbers	V_{BR}		V_{RM}	I_R	I_{PP} 8/20 μ s pulse; notes 1 and 2	V_{CL} (Max)		C $f=1\text{MHz};$ $V_R = 0\text{ V};$ see Fig.4
	Min.	Max.				@ $I_{PP}=1\text{A}$	@ $I_{PP}=2.5\text{A}$	
	v	v		μA		v	v	
LESDA5VAW6T1G	6.4	7.2	5	1	2.5	10	12	15

Notes

1. Non-repetitive current pulse 8/20 μ s exponentially decaying waveform; see Fig.1.
2. Measured from any of pins 1, 3, 4, 5 or 6 to pin 2.

GRAPHICAL DATA

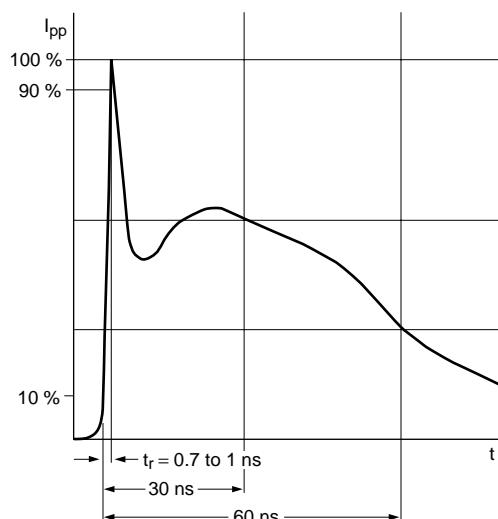
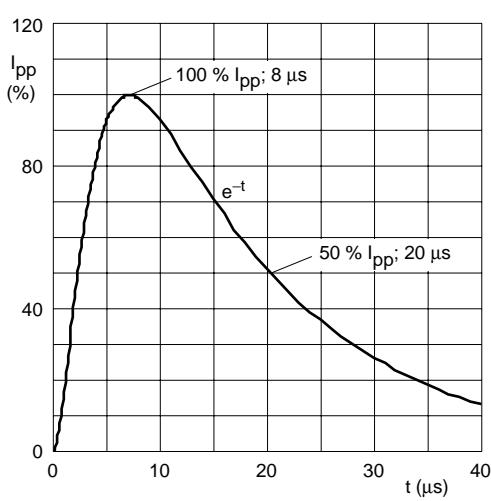
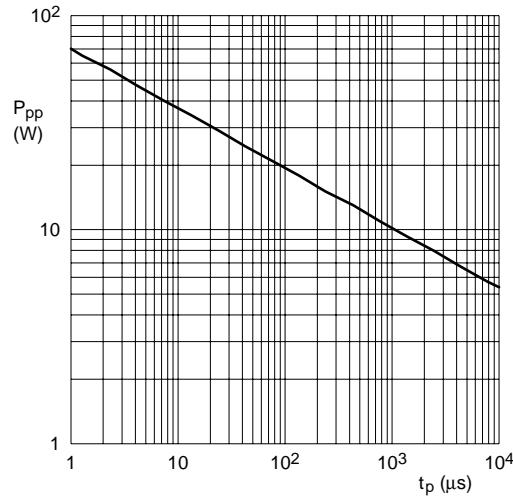


Fig.1 8/20 μ s pulse waveform according to IEC 61000-4-5.

Fig.2 Electrostatic Discharge (ESD) pulse waveform according to IEC 61000-4-2.

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GRAPHICAL DATA



$T_{amb} = 25^\circ\text{C}$.

$I_{pp} = 8/20 \mu\text{s}$ exponentially decaying waveform; see Fig.1.

Fig.3 Peak pulse power dissipation as a function of pulse time; typical values.

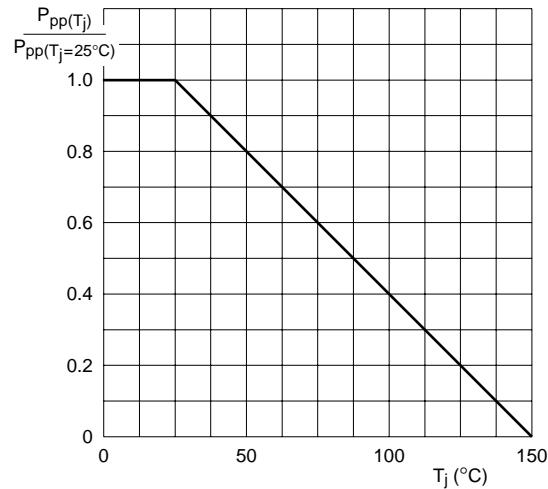
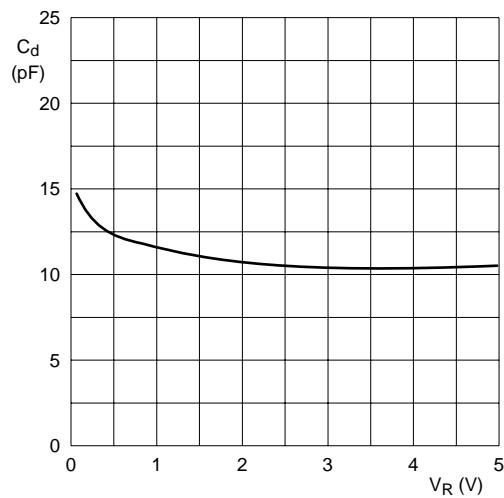


Fig.4 Relative variation of peak pulse power as a function of junction temperature; typical values.



$f = 1 \text{ MHz}; T_{amb} = 25^\circ\text{C}$.

Fig.5 Diode capacitance as a function of reverse voltage; typical values.

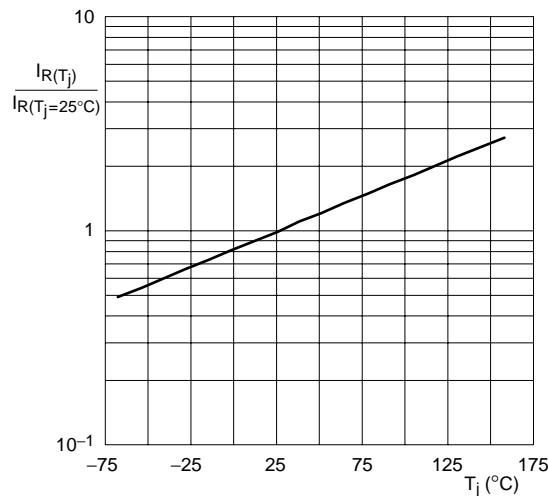
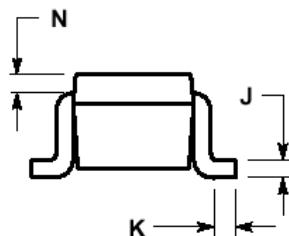
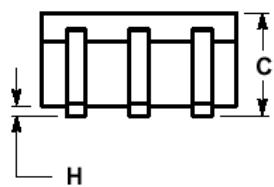
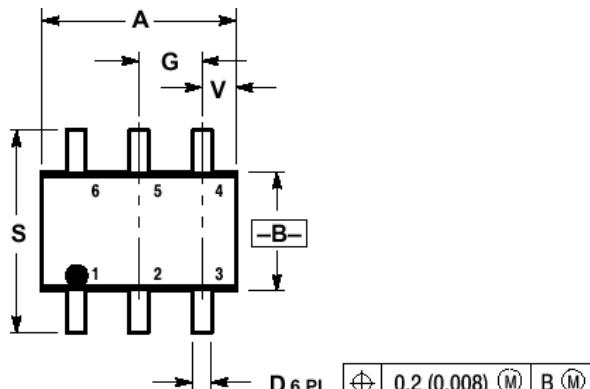


Fig.6 Relative variation of reverse leakage current as a function of junction temperature; typical values.

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PACKAGE DIMENSIONS

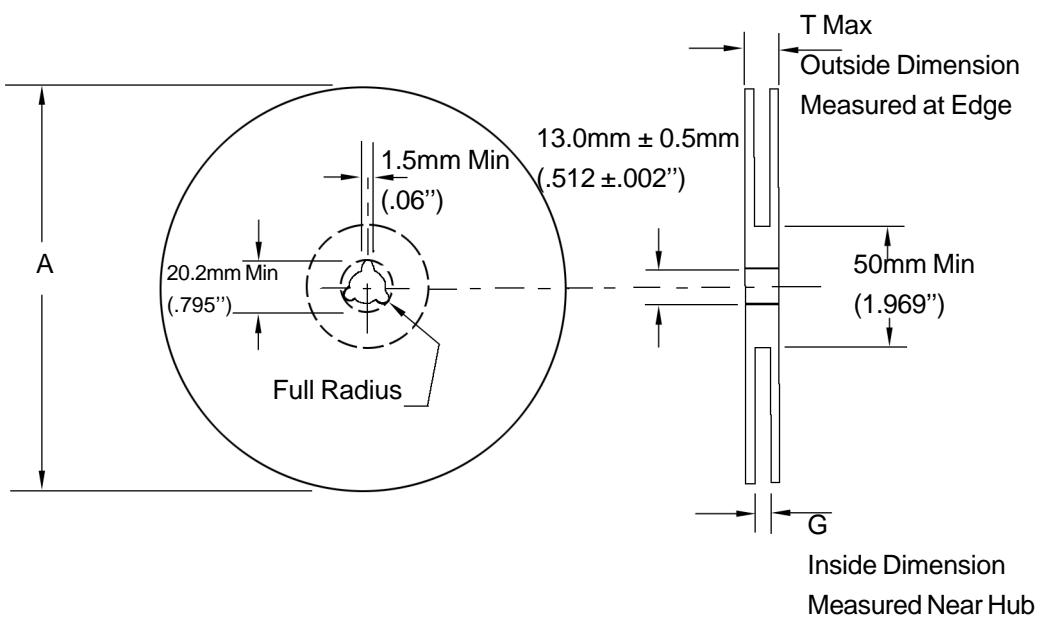
SC-88/SOT-363


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026BSC		0.65BSC	
H	—	0.004	—	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20
V	0.012	0.016	0.30	0.40

EMBOSSSED TAPE AND REEL DATA FOR DISCRETES



Size	A Max	G	T Max
8 mm	178.0mm (7.0")	8.4mm+1.5mm, -0.0 (.33"+.039", -.00)	10.9mm (.43")

Reel Dimensions

Metric Dimensions Govern — English are in parentheses for reference only

Storage Conditions

Temperature: 5 to 40 Deg.C (20 to 30 Deg. C is preferred)

Humidity: 30 to 80 RH (40 to 60 is preferred)

Recommended Period: One year after manufacturing

(This recommended period is for the soldering condition only. The characteristics and reliabilities of the products are not restricted to this limitation)

Shipment Specification

